

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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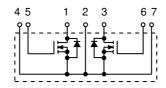


Dual Power MOSFET Module

VMK 165-007T

 $V_{DSS} = 70 V$ $I_{D25} = 165 A$ $R_{DS(on)} = 7 m\Omega$

Common-Source connected N-Channel Enhancement Mode



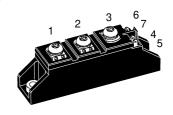
Symbol	Conditions		Maximum	Maximum Ratings		
V _{DSS}	T _J = 25°C to 150°C		70	V		
V_{DGR}	$T_J = 25^{\circ}C \text{ to } 150^{\circ}C; R_{GS}$	= $6.8 \text{ k}\Omega$	70	V		
V_{GS}	Continuous		±20	V		
V _{GSM}	Transient		±30	V		
I _{D25}	$T_{c} = 25^{\circ}C$		165	A		
I _D	$T_C = 100^{\circ}C$		104	Α		
I _{DM}	$T_{C} = 25^{\circ}C, t_{p} = 10 \mu s, p$	ulse width lim	ited by T _{JM} 660	Α		
P _{tot}	$T_{C} = 25^{\circ}C, T_{J} = 150^{\circ}C$		390	W		
T,			-40 +150	°C		
T _{JM}			150	°C		
T _{stg}			-40 +125	°C		
V _{ISOL}	50/60 Hz	t = 1 min	3000	V~		
.002	$I_{ISOL} \le 1 \text{ mA}$	t = 1 s	3600	V~		
M _d	Mounting torque(M5 or 1	0-32 UNF)	2.5-4.0/22-35	Nm/lb.in.		
-	Terminal connection torq	ue (M5)	2.5-4.0/22-35	Nm/lb.in.		
Weight	Typical including screws		90	g		

Symbol	Conditions	Characteristic Values (T _J = 25°C, unless otherwise specified)			
		min.	typ.	max.	
V _{DSS}	$V_{GS} = 0 \text{ V}, I_D = 1 \text{ mA}$	70			٧
V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 8 \text{ mA}$	2		4	V

			-716-	
V _{DSS} V _{GS(th)}	$V_{GS} = 0 \text{ V}, I_{D} = 1 \text{ mA}$ $V_{DS} = V_{GS}, I_{D} = 8 \text{ mA}$	70 2		4 V
I _{GSS}	$V_{GS} = \pm 20 \text{ V DC}, V_{DS} = 0$			500 nA
I _{DSS}	$\begin{array}{llllllllllllllllllllllllllllllllllll$			200 μA 1 mA
R _{DS(on)}	$V_{GS} = 10 \text{ V}, I_D = 0.5 \cdot I_{D25}$ Pulse test, t $\leq 300 \mu\text{s}$, duty cycle d $\leq 2 \%$		6	7 mΩ

Data per MOSFET unless otherwise stated.





1, 3 = Drain, 5, 6 = Gate, 2 = Common Source 4, 7 = Kelvin Source

Features

- · Two MOSFET with common source
- International standard package JEDEC TO-240 AA
- Direct copper bonded Al₂O₃ ceramic base plate
- · Isolation voltage 3000 V~
- Low $R_{DS(on)}$ HDMOSTM process
- Low package inductance for high speed switching
- · Kelvin source contact
- · Keyed twin plugs

Applications

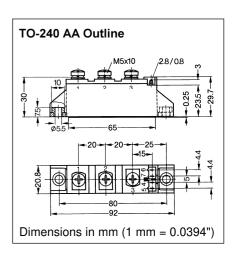
- · Push-pull inverters
- Switched-mode and resonant-mode power supplies
- · Uninterruptible power supplies (UPS)
- AC static switches

Advantages

- · Easy to mount with two screws
- · Space and weight savings
- · High power density
- · Low losses



Symbol	Conditions Ch (T _J = 25°C, unless		istic Values
	min.	typ.	max.
g _{fs}	$V_{DS} = 10 \text{ V}; I_{D} = 0.5 \cdot I_{D25} \text{ pulsed}$ 60	80	S
C _{iss} C _{oss} C _{rss}		8.8 4.0 2.4	nF nF nF
$\mathbf{t_{d(on)}}$ $\mathbf{t_r}$ $\mathbf{t_{d(off)}}$ $\mathbf{t_f}$	$\begin{cases} V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \bullet V_{DSS}, I_D = 0.5 \bullet I_{D25} \\ R_G = 1 \Omega \text{ (External), resistive load} \end{cases}$	120 280 390 110	ns ns ns
$egin{array}{c} oldsymbol{Q}_{g} \ oldsymbol{Q}_{gs} \ oldsymbol{Q}_{gd} \ \end{array}$		480 60 240	nC nC nC
$R_{ ext{thJC}}$	with heat transfer paste	0.2	0.32 K/W K/W
d _s d _A a	Creepage distance on surface 12.7 Strike distance through air 9.6 Max. allowable acceleration	50	mm mm m/s²



Source-Drain Diode

Characteristic Values

 $(T_J = 25^{\circ}C, \text{ unless otherwise specified})$ **min.** | **typ.** | **max.**

Symbol	Conditions	nin.	typ.	max.	,
I _s	V _{GS} = 0 V			165	A
I _{SM}	Repetitive; pulse width limited by T _{JM}			660	A
V _{SD}	$\begin{split} I_F &= I_S; \ V_{GS} = 0 \ V, \\ \text{Pulse test, } t \leq 300 \ \mu\text{s, duty cycle d} \leq 2 \ \% \end{split}$			1.5	V
t _{rr}	$I_F = 50 \text{ A}$, -di/dt = 200 A/ μ s, $V_{DS} = 25 \text{ V}$, $V_{GS} = 0 \text{ V}$		150		ns